











TXS0108E-Q1

ZHCSDZ8A - JUNE 2015 - REVISED FEBRUARY 2016

TXS0108E-Q1面向开漏和推挽应用的 8 位双向电压电平转换 转换器

特性

- 符合汽车类应用的 AEC-Q100 标准
 - 器件温度等级 1: -40°C 至 125°C
 - 器件人体放电模式 (HBM) 静电放电 (ESD) 分类
 - 器件组件充电模式 (CDM) ESD 分类等级 C6
- 无需方向控制信号
- 最大数据速率
 - 110Mbps (推挽)
 - 1.2Mbps (开漏)
- A端口 1.4V 至 3.6V; B端口 1.65V 至 5.5V (V_{CCA} ≤ V_{CCB})
- 无需电源排序 V_{CCA} 或 V_{CCB} 均可优先斜升
- 锁断性能超过 100mA, 符合 JESD 78 II 类规范的要求
- 静电放电 (ESD) 保护性能超过 JESD 22 规范的要 求(A端口)
 - 2000V 人体放电模式 (A114-B)
 - 1000V 充电器件模型 (C101)
- IEC 61000-4-2 ESD (B 端口)
 - ±8kV 接触放电
 - ±6kV 气隙放电

3 说明

这款 8 位非反向转换器使用两个独立的可配置电源 轨。A端口跟踪 V_{CCA} 引脚的电源电压。V_{CCA} 引脚可 接受 1.4V 到 3.6V 范围内的任意电源电压。B 端口跟 踪 V_{CCB} 引脚的电源电压。 V_{CCB} 引脚可接受 1.65V 到 5.5V 范围内的任意电源电压。这两个输入电源引脚可 实现 1.5V、1.8V、2.5V、3.3V 和 5V 电压节点之间的 任意低压双向转换。

输出使能 (OE) 输入为低电平时, 所有输出均将置于高 阻抗 (Hi-Z) 状态。

为确保输出在上电或断电期间处于 Hi-Z 状态, 需通过 一个下拉电阻将 OE 接至 GND。该电阻的最小值取决 于驱动器的拉电流能力。

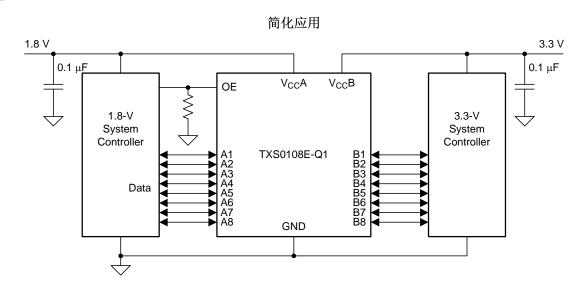
器件信息⁽¹⁾

器件型号	封装	封装尺寸 (标称值)
TXS0108E-Q1	TSSOP (20)	6.50mm x 6.40mm

(1) 如需了解所有可用封装,请参见数据表末尾的可订购产品附

2 应用

汽车





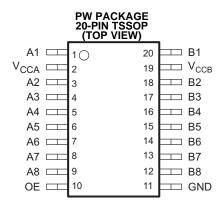
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4 修订历史记录

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•	已更改引脚功能	



5 Pin Configuration and Functions



Pin Functions

P	rIN	TYPE ⁽¹⁾	DECORPORTION
NAME	NO.	IYPE	DESCRIPTION
A1	1	I/O	Input/output 1. Referenced to V _{CCA}
A2	3	I/O	Input/output 2. Referenced to V _{CCA}
A3	4	I/O	Input/output 3. Referenced to V _{CCA}
A4	5	I/O	Input/output 4. Referenced to V _{CCA}
A5	6	I/O	Input/output 5. Referenced to V _{CCA}
A6	7	I/O	Input/output 6. Referenced to V _{CCA}
A7	8	I/O	Input/output 7. Referenced to V _{CCA}
A8	9	I/O	Input/output 8. Referenced to V _{CCA}
B1	20	I/O	Input/output 1. Referenced to V _{CCB}
B2	18	I/O	Input/output 2. Referenced to V _{CCB}
B3	17	I/O	Input/output 3. Referenced to V _{CCB}
B4	16	I/O	Input/output 4. Referenced to V _{CCB}
B5	15	I/O	Input/output 5. Referenced to V _{CCB}
B6	14	I/O	Input/output 6. Referenced to V _{CCB}
B7	13	I/O	Input/output 7. Referenced to V _{CCB}
B8	12	I/O	Input/output 8. Referenced to V _{CCB}
GND	11	G	Ground
OE	10	I	3-state output-mode enable. Pull OE low to place all outputs in 3-state mode. Referenced to V _{CCA} .
V_{CCA}	2	I	A-port supply voltage. 1.5 V \leq V _{CCA} \leq 3.6 V, V _{CCA} \leq V _{CCB} .
V_{CCB}	19	I	B-port supply voltage. 1.65 V ≤ V _{CCB} ≤ 5.5 V.

⁽¹⁾ I = Input, O = Output, I/O = Bi-directional, G = Ground



6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CCA}	O mark consists and		-0.5	4.6	V
V _{CCB}	Supply voltage		-0.5	5.5	V
	January (2)	A port	-0.5	4.6	V
V _I	Input voltage (2)	B port	-0.5	6.5	V
	Voltage range applied to any output	A port	-0.5	4.6	V
Vo	in the high-impedance or power-off state ⁽²⁾	B port	-0.5	6.5	
\ /	Valtage range emplied to any output in the high or law state (2) (3)	A port	-0.5	V _{CCA} + 0.5	V
Vo	Voltage range applied to any output in the high or low state (2) (3)	B port	-0.5	V _{CCB} + 0.5	
I _{IK}	Input clamp current	V _I < 0		-50	mA
l _{ok}	Output clamp current	V _O < 0		-50	mA
lo	Continuous output current		-50	50	mA
	Continuous current through V _{CCA} , V _{CCB} , or GND		-100	100	mA
T _{stg}	Storage temperature	-65	150	°C	

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	±2000	V
	discharge	Charged-device model (CDM), per AEC Q100-011	±1000	V

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

⁽²⁾ The input and output negative Voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The value of V_{CCA} and V_{CCB} are provided in the recommended operating conditions table.



6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted) (1)(2)

			V _{CCA} (V)	V _{CCB} (V)	MIN	MAX	UNIT	
V _{CCA}	Supply voltage ⁽³⁾				1.4	3.6	V	
V_{CCB}	Supply Voltage (**)				1.65	5.5	V	
		A-Port I/Os	1.4 to 1.95		V _{CCI} - 0.2	V_{CCI}		
V	High-level input voltage	A-POR I/OS	1.95 to 3.6		V _{CCI} - 0.4	V_{CCI}	V	
V_{IH}		B-Port I/Os	1.4 to 3.6		V _{CCI} - 0.4	V_{CCI}	V	
		OE	1.4 10 3.0		$V_{CCA} \times 0.65$	5.5		
		A-Port I/Os	1.4 to 1.95	1.65 to 5.5	0	0.15	V	
V	Low-level input	A-POILI/OS	1.95 to 3.6		0	0.15		
V_{IL}	voltage	B-Port I/Os	4.4.4.00		0	0.15	V	
		OE	1.4 to 3.6		0	$V_{CCA} \times 0.35$		
		A-Port I/Os Push-pull						
Δt/Δν	Input transition rise or fall rate	B-Port I/Os Push-pull	1.4 to 3.6			10	ns/V	
	idii idio	Control input						
T _A	Operating free-air temp	perature			-40	125	°C	

6.4 Thermal Information

		TXS0108E-Q1	
	THERMAL METRIC ⁽¹⁾	PW (TSSOP)	UNIT
		20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	101.5	
R ₀ JC(top)	Junction-to-case (top) thermal resistance	35.9	
$R_{\theta JB}$	Junction-to-board thermal resistance	52.4	900
ΨЈТ	Junction-to-top characterization parameter	2.3	°C/W
ΨЈВ	Junction-to-board characterization parameter	51.9	
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	_	

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

 $[\]begin{array}{lll} \hbox{(1)} & V_{CCI} \ \hbox{is the} \ V_{CC} \ \hbox{associated with the data input port.} \\ \hbox{(2)} & V_{CCO} \ \hbox{is the} \ V_{CC} \ \hbox{associated with the output port.} \\ \hbox{(3)} & V_{CCA} \ \hbox{must be less than or equal to} \ V_{CCB}, \ \hbox{and} \ V_{CCA} \ \hbox{must not exceed 3.6 V.} \\ \end{array}$



6.5 Electrical Characteristics (1)(2)(3)

over recommended operating free-air temperature range (unless otherwise noted)

DADA	METER	TEST	V 00	V 00		T _A = 25°C		$T_A = -40$ °C to	125°C	UNIT	
PARA	MILIER	CONDITIONS	V _{CCA} (V)	V _{CCB} (V)	MIN	TYP	MAX	MIN	MAX	ONT	
V_{OHA}		$I_{OH} = -20 \mu A,$ $V_{IB} \ge V_{CCB} - 0.4 V$	1.4 to 3.6	1.65 to 5.5				V _{CCA} × 0.67		٧	
		$I_{OL} = 180 \ \mu A, \ V_{IB} \le 0.15 \ V$	1.4						0.4		
V _{OLA}		$I_{OL} = 220 \ \mu A, \ V_{IB} \le 0.15 \ V$	1.65	1.65 to 5.5					0.4	V	
VOLA		$I_{OL} = 300 \ \mu A, \ V_{IB} \le 0.15 \ V$	2.3	1.00 (0 5.5					0.4	v	
		$I_{OL} = 400 \ \mu A, \ V_{IB} \le 0.15 \ V$	3						0.55		
V _{OHB}		$I_{OH} = -20 \mu A,$ $V_{IA} \ge V_{CCA} - 0.2 V$	1.4 to 3.6	1.65 to 5.5				V _{CCB} × 0.67		V	
		$I_{OL} = 220 \ \mu A, \ V_{IA} \le 0.15 \ V$		1.65	·				0.4		
V_{OLB}		$I_{OL} = 300 \ \mu A, \ V_{IA} \le 0.15 \ V$	1.440.26	2.3					0.4	V	
		$I_{OL} = 400 \ \mu A, \ V_{IA} \le 0.15 \ V$	1.4 to 3.6	3					0.55	V	
		I _{OL} = 620 μA, V _{IA} ≤ 0.15 V		4.5					0.55		
ı	OE	V _I = V _{CCI} or GND	1.4	1.65 to 5.5	-1		1		2	μΑ	
oz	A or B port		1.4	1.65 to 5.5	-1		1	-2	2	μA	
	·		1.4 to 3.6	2.3 to 5.5					2		
CCA		$V_I = V_O = Open, I_O = 0$	3.6	0					2	μΑ	
			0	5.5					-1		
			1.4 to 3.6	2.3 to 5.5					6		
ССВ		$V_I = V_O = Open, I_O = 0$	3.6	0					-1	μΑ	
			0	5.5					1.5		
_{CCA} + I _{CC}	СВ	$V_I = V_{CCI}$ or GND, $I_O = 0$	1.4 to 3.6	2.3 to 5.5					8	μΑ	
I _{CCZA}		$V_I = V_O = Open,$ $I_O = 0$, OE = GND	1.4 to 3.6	1.65 to 5.5					2	μA	
CCZB		$V_I = V_O = Open,$ $I_O = 0$, OE = GND	1.4 to 3.6	1.65 to 5.5					6	μА	
C _i	OE		3.3	3.3		4.5			6.75	pF	
^	A port		2.2	2.2		6			7.6	nE	
C_{io}	B port		3.3	3.3		5.5			6.9	pF	

6.6 Timing Requirements: $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$ (unless otherwise noted)

				V _{CC B} = 1.8 V ± 0.15 V		V _{CC B} = 2.5 V ± 0.2 V		V _{CC B} = 3.3 V ± 0.3 V		V _{CC B} = 5 V ± 0.5 V		UNIT	
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
	Data rate	Push-pull			40		60		60		60		
	Open-drain				0.8		0.8		1		1	Mbps	
t _w	Dulas dunation	Push-pull	Data innuta	25		16.7		16.7		16.7			
	Pulse duration	Open-drain	Data inputs	1250		1250		1000		1000		ns	

 $[\]begin{array}{ll} \hbox{(1)} & V_{CCO} \text{ is the } V_{CC} \text{ associated with the output port.} \\ \hbox{(2)} & V_{CCI} \text{ is the } V_{CC} \text{ associated with the input port.} \\ \hbox{(3)} & V_{CCA} \text{ must be less than or equal to } V_{CCB}, \text{ and } V_{CCA} \text{ must not exceed 3.6 V.} \\ \end{array}$



6.7 Timing Requirements: $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted)

				V _{CC B} = 1.8 V ± 0.15 V		V _{CC B} = 2.5 V ± 0.2 V		V _{CC B} = 3.3 V ± 0.3 V		V _{CC B} = 5 V ± 0.5 V		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	Data rate Push-pull Open-drain				45		65		70		70	Mbps
					8.0		8.0		8.0		1	MDPS
	Pulse duration	Push-pull	Data innuta	22.2		15.3		15.3		15.3		2
t _w		Open-drain	Data inputs	1250		1250		1250		1000		ns

6.8 Timing Requirements: $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted)

					V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V	
				MIN	MAX	MIN	MAX	MIN	MAX	
	Data sata	Push-pull			80		95		100	N 41
	Data rate	Open-drain			0.8		8.0		1	Mbps
	Pulse duration	Push-pull	Data innuta	12.5		10.5		10		
ı _w		Open-drain	Data inputs	1250		1250		1000		ns

6.9 Timing Requirements: $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$

over recommended operating free-air temperature range, V_{CCA} = 3.3 V ± 0.3 V (unless otherwise noted)

		$V_{CCB} = 3.3 \text{ V} $ $V_{CC} = 5 \text{ V} $ $\pm 0.3 \text{ V} $ $\pm 0.5 \text{ V} $						UNIT
				MIN	MAX	MIN	MAX	
	Data rate	Push-pull		100		110	Mhno	
	Data fate	Open-drain		8.0		1.2	Mbps	
	Pulse duration	Push-pull	Data inputs	10		9.1		5
ι _W	Pulse duration	Open-drain	Data inputs	1250		833		ns



6.10 Switching Characteristics: $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$ (unless otherwise noted)

PARA	FROM	то	TEST CONDITIO	V _{CCB} = 1 ± 0.15	1.8 V 5 V	V _{CCB} = ± 0.2	2.5 V ! V	V _{CCB} = ± 0.3	3.3 V V	V _{CCB} = ± 0.5	5 V V	UNIT	
METER	(INPUT)	(OUTPUT)	N (DRIVING)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	0	
			Push-pull		11		9.2		8.6		8.6		
t _{PHL}	Α	В	Open-drain	2.5	14.4	2	12.8	2	12.2	1.9	12	ns	
	A	Б	Push-pull		12		10		9.8		9.7	113	
t _{PLH}			Open-drain	0.9	720	0.9	554	1	473	1.5	384		
			Push-pull		12.7		11.1		11		12		
t _{PHL}	В	A O	Open-drain	3.4	13.2	2.6	9.6	2.3	8.5	2	7.5	20	
		A	Push-pull		9.5		6.2		5.1		4.2	ns	
t _{PLH}			Open-drain		745		603		519		407		
t _{en}	OE	A or B	Duch null		480		480		480		480	ns	
t _{dis}	OE	A or B	Push-pull		400		400		400		400	ns	
4	A part rise tir	20	Push-pull	3	13.1	2.4	9.8	2	9	2	8.9	ns	
t _{rA}	A-port rise tir	iie	Open-drain	220	982	180	716	140	592	100	481	115	
	D nort rice tir		Push-pull	2.6	11.4	1.6	7.4	1	6	0.7	5	20	
t _{rB}	B-port rise tir	ne	Open-drain	220	1020	150	756	100	653	40	370	ns	
	A nort fall tim	A-port fall time		2.3	9.9	1.7	7.7	1.6	6.8	1.7	6		
t _{fA}	A-port rail tim			2.4	10	1.8	8.2	1.7	9	1.5	9.15	20	
	D port fall tim		Push-pull	2	8.7	1.3	5.5	1	3.8	1	3.1	ns	
t _{fB}	B-port fall time		Open-drain	2	11.5	1.3	8.6	1	9.6	1	7.7		
t _{SK(O)}	Channel-to-c	Channel-to-channel skew			1		1		1		1	ns	



6.11 Switching Characteristics: $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted)

PARA- METER	FROM (INPUT)	TO (OUTPUT	TEST CONDITION	V _{CCB} = ± 0.1	1.8 V 5 V	V _{CCB} = 2 ± 0.2	.5 V V	V _{CCB} = 3 ± 0.3	.3 V V	V _{CCB} = ± 0.5	5 V V	UNIT	
WILTER	(INFOT))	(DRIVING)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
			Push-pull		8.2		6.4		5.7		5.6		
t _{PHL}	^	В	Open-drain	2.1	11.4	1.7	9.9	1.6	9.3	1.5	8.9		
	A	В	Push-pull		9		5.6		6.5		6.3	ns	
t _{PLH}			Open-drain	0.15	729	0.2	584	0.3	466	0.3	346		
		Push-pull		9.8		8		7.4		7			
t _{PHL}	D		Open-drain	3.19	12.1	2	8.5	1.9	7.3	1.8	6.2		
	PLH		A	Push-pull		10.2		7		5.8		5	ns
t _{PLH}			Open-drain		733		578		459		323		
t _{en}	OE	A or B	5		100		100		100		100	ns	
t _{dis}	OE	A or B	Push-pull		410		410		410		410	ns	
	A		Push-pull	2.7	11.9	2	8.6	1.9	7.8	1.8	7.4		
t _{rA}	A-port i	rise time	Open-drain	250	996	200	691	150	508	110	365	ns	
	D	d= = 4!	Push-pull	2.5	10.5	1.7	7.4	1.1	5.3	60	4.7		
t _{rB}	B-port i	rise time	Open-drain	250	1001	170	677	120	546	32	323	ns	
	A	f=11 4!	Push-pull	2.1	8.8	1.6	7.1	1.4	6.8	1.4	6.06		
t _{fA}	A-port	fall time	Open-drain	2.2	9	1.7	7.2	1.4	6.8	1.2	6.1		
	D	f = 11 4!	Push-pull	2	8.3	1.3	5.4	0.9	3.9	0.7	3	ns	
t _{fB}	B-port fall time		Open-drain	2	10.5	1	10.7	1	9.6	0.6	7.8		
t _{SK(O)}	Channel-to-channel skew		Push-pull		1		1		1		1	ns	



6.12 Switching Characteristics: $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted)

PARA- METER	FROM	TO (OUTPUT)	TEST CONDITION	V _{CCB} = 2. ± 0.2 V	5 V	V _{CCB} = 3. ± 0.3 \	3 V	V _{CCB} = 5 ± 0.5 V	5 V	UNIT
WEIER	(INPUT)	(001701)	(DRIVING)	MIN	MAX	MIN	MAX	MIN	MAX	
			Push-pull		5		4		3.7	
t _{PHL}	^	В	Open-drain		6.2		6.3	6.3		
4	Α	В	Push-pull		5.2		4.3		3.9	ns
t _{PLH}			Open-drain		5		17.5		15.5	
4			Push-pull		5.4		4.7		4.2	
t _{PHL}		^	Open-drain		7.3		6		4.9	
	В	Α	Push-pull		5.9		4.4		3.5	ns
t _{PLH}			Open-drain		5		5	5		
t _{en}	OE	A or B	December and I		100		100		100	ns
t _{dis}	OE	A or B	Push-pull		400		400		400	ns
	A nort rice t		Push-pull	1.89	7.3	1.6	6.4	1.5	5.8	
t _{rA}	A-port rise t	ume	Open-drain	110.00	692	157	529	116	377	ns
	D		Push-pull	1.70	6.5	1.3	5.1	0.9	4.32	
t _{rB}	B-port rise t	ime	Open-drain	107.00	693	140	483	77	304	ns
	A		Push-pull	1.50	5.7	1.2	4.7	1.3	3.8	
t_{fA}	A-port fall ti	me	Open-drain	1.50	5.6	1.2	4.7	1.1	4.2	
1	D now fall ti		Push-pull	1.40	5.4	0.9	4.1	0.7	3	ns
t_{fB}	B-port fall ti	me	Open-drain	0.40	14.2	0.5	19.4	0.4	3	
t _{SK(O)}	Channel-to- skew	channel	Push-pull		1		1		1	ns



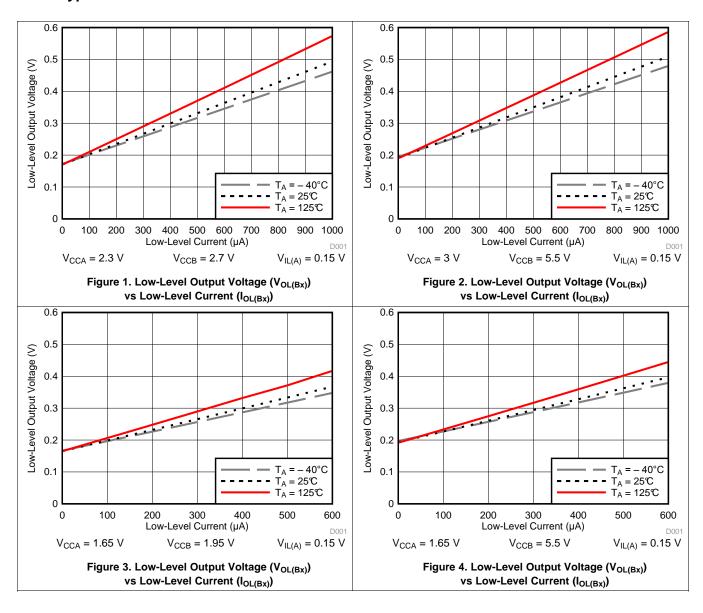
6.13 Switching Characteristics: $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted)

PARAME FROM TER (INPUT)		TO (OUTPUT)	TEST CONDITION	V _{CCB} = 3 ± 0.3 V	3 V	V _{CCB} = 5 ± 0.5 V	V	UNIT
IEK	(INPUT)	(OUTPUT)	(DRIVING)	MIN	MAX	MIN	MAX	
			Push-pull		3.8		3.28	
t _{PHL}	^	D	Open-drain		5.3		4.8	
	A	В	Push-pull		3.9		3.5	ns
t _{PLH}			Open-drain		5			
			Push-pull		4.2		3.8	
t _{PHL}	В	^	Open-drain		5.5		4.5	ns
	Б	Α	Push-pull	4.32			4.3	
t _{PLH}			Open-drain		5		5	
t _{en}	OE	A or B	Duch null		100		100	ns
t _{dis}	OE	A or B	Push-pull		400		400	ns
	A part rice time		Push-pull	1.5	5.7	1.4	5	ns
t _{rA}	A-port rise time		Open-drain	129	446	99.6	337	115
	D nort rice time		Push-pull	1.35	5	1	4.24	
t _{rB}	B-port rise time		Open-drain	129	427	77	290	ns
	A nort fall time		Push-pull	1.4	4.5	1.3	3.5	
t _{fA}	A-port fall time		Open-drain	1.4	4.4	1.2	3.7	20
	D nort fall time		Push-pull	1.3	4.2	1.1	3.1	ns
t_{fB}	p-hou ian rime	B-port fall time		1.3	4.2	1.1	3.1	
t _{SK(O)}	Channel-to-channe	el skew	Push-pull		1		1	ns

TEXAS INSTRUMENTS

6.14 Typical Characteristics





7 Parameter Measurement Information

7.1 Load Circuits

Figure 5 shows the push-pull driver circuit used for measuring data rate, pulse duration, propagation delay, output rise-time and fall-time. Figure 6 shows the open-drain driver circuit used for measuring data rate, pulse duration, propagation delay, output rise-time and fall-time.

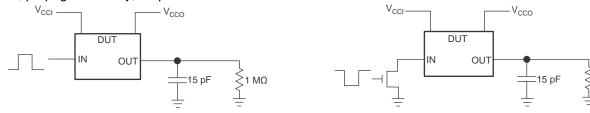
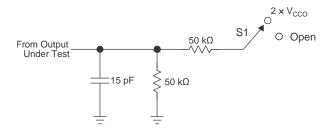


Figure 5. Data Rate, Pulse Duration, Propagation Delay, Output Rise-Time and Fall-Time Measurement Using a Push-Pull Driver

Figure 6. Data Rate (10 pF), Pulse Duration (10 pF), Propagation Delay, Output Rise-Time and Fall-Time Measurement Using an Open-Drain Driver



TEST	S1
1 - 0 1	01
t_{PZL} / t_{PLZ} (t_{dis})	2 × V _{CCO}
t _{PHZ} / t _{PZH} (t _{en})	Open

Figure 7. Load Circuit for Enable-Time and Disable-Time Measurement

- 1. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- 2. t_{PZL} and t_{PZH} are the same as t_{en} .
- 3. V_{CCI} is the V_{CC} associated with the input port.
- 4. V_{CCO} is the V_{CC} associated with the output port.



7.2 Voltage Waveforms

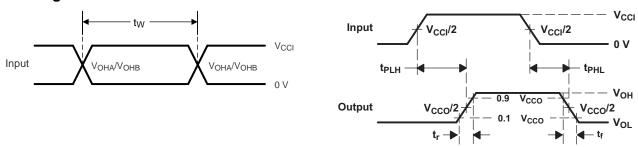


Figure 8. Pulse Duration (Push-Pull)

Figure 9. Propagation Delay Times

- C_L includes probe and jig capacitance.
- Waveform 1 in Figure 10 is for an output with internal such that the output is high, except when OE is high (see Figure 7). Waveform 2 in Figure 10 is for an output with conditions such that the output is low, except when OE is high.
- All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, dv/dt ≥ 1 V/ns.
- · The outputs are measured one at a time, with one transition per measurement.
- t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- t_{PZL} and t_{PZH} are the same as t_{en}.
- t_{PLH} and t_{PHL} are the same as t_{pd}.
- V_{CCI} is the V_{CC} associated with the input port.
- V_{CCO} is the V_{CC} associated with the output port.

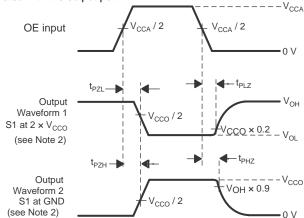


Figure 10. Enable and Disable Times

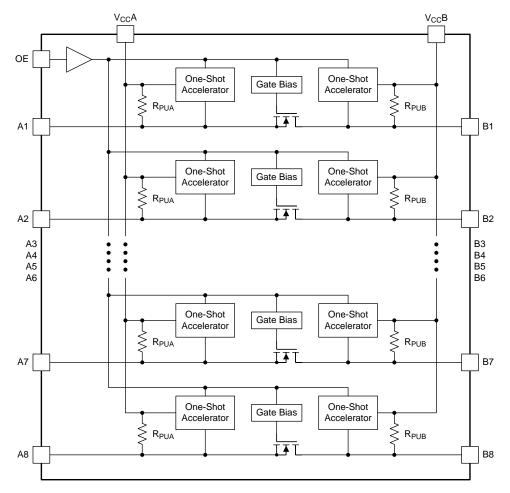


8 Detailed Description

8.1 Overview

The TXS0108E-Q1 device is a directionless voltage-level translator specifically designed for translating logic voltage levels. The A-port accepts I/O voltages ranging from 1.4 V to 3.6 V. The B-port accepts I/O voltages from 1.65 V to 5.5 V. The device uses pass gate architecture with edge rate accelerators (one shots) to improve the overall data rate. The pull-up resistors, commonly used in open-drain applications, have been conveniently integrated so that an external resistor is not needed. While this device is designed for open-drain applications, the device can also translate push-pull CMOS logic outputs.

8.2 Functional Block Diagram



Each A-port I/O has a pull-up resistor (R_{PUA}) to V_{CCA} and each B-port I/O has a pull-up resistor (R_{PUB}) to V_{CCB} . R_{PUA} and R_{PUB} have a value of 40 k Ω when the output is driving low. R_{PUA} and R_{PUB} have a value of 4 k Ω when the output is driving high. R_{PUA} and R_{PUB} are disabled when OE = Low.

8.3 Feature Description

8.3.1 Architecture

Figure 11 describes semi-buffered architecture design this application requires for both push-pull and open-drain mode. This application uses edge-rate accelerator circuitry (for both the high-to-low and low-to-high edges), a high-on-resistance N-channel pass-gate transistor (on the order of 300 Ω to 500 Ω) and pull-up resistors (to provide DC-bias and drive capabilities) to meet these requirements. This design needs no direction-control signal (to control the direction of data flow from A to B or from B to A). The resulting implementation supports both low-speed open-drain operation as well as high-speed push-pull operation.

Feature Description (continued)

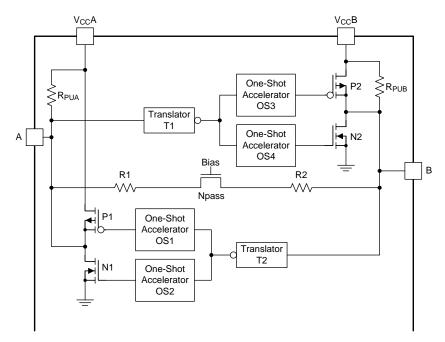


Figure 11. Architecture of a TXS0108E-Q1 Cell

When transmitting data from A-ports to B-ports, during a rising edge the one-shot circuit (OS3) turns on the PMOS transistor (P2) for a short-duration which reduces the low-to-high transition time. Similarly, during a falling edge, when transmitting data from A to B, the one-shot circuit (OS4) turns on the N-channel MOSFET transistor (N2) for a short-duration which speeds up the high-to-low transition. The B-port edge-rate accelerator consists of one-shot circuits OS3 and OS4. Transistors P2 and N2 and serves to rapidly force the B port high or low when a corresponding transition is detected on the A port.

When transmitting data from B- to A-ports, during a rising edge the one-shot circuit (OS1) turns on the PMOS transistor (P1) for a short-duration which reduces the low-to-high transition time. Similarly, during a falling edge, when transmitting data from B to A, the one-shot circuit (OS2) turns on NMOS transistor (N1) for a short-duration and this speeds up the high-to-low transition. The A-port edge-rate accelerator consists of one-shots OS1 and OS2, transistors P1 and N1 components and form the edge-rate accelerator and serves to rapidly force the A port high or low when a corresponding transition is detected on the B port.

8.3.2 Input Driver Requirements

The continuous DC-current *sinking* capability is determined by the external system-level open-drain (or push-pull) drivers that are interfaced to the TXS0108E-Q1 I/O pins. Because the high bandwidth of these bidirectional I/O circuits is used to facilitate this fast change from an input to an output and an output to an input, they have a modest DC-current *sourcing* capability of hundreds of micro-amperes, as determined by the internal pull-up resistors.

The fall time (t_{fA} , t_{fB}) of a signal depends on the edge-rate and output impedance of the external device driving TXS0108E-Q1 data I/Os, as well as the capacitive loading on the data lines.

Similarly, the t_{PHL} and maximum data rates also depend on the output impedance of the external driver. The values for t_{fA} , t_{fB} , t_{PHL} , and maximum data rates in the data sheet assume that the output impedance of the external driver is less than 50 Ω .



Feature Description (continued)

8.3.3 Output Load Considerations

TI recommends careful PCB layout practices with short PCB trace lengths to avoid excessive capacitive loading and to ensure that proper one-shot triggering takes place. PCB signal trace-lengths should be kept short enough such that the round trip delay of any reflection is less than the one-shot duration. This improves signal integrity by ensuring that any reflection sees a low impedance at the driver. The one-shot circuits have been designed to stay on for approximately 30 ns. The maximum capacitance of the lumped load that can be driven also depends directly on the one-shot duration. With very heavy capacitive loads, the one-shot can time-out before the signal is driven fully to the positive rail. The one-shot duration has been set to best optimize trade-offs between dynamic I_{CC} , load driving capability, and maximum bit-rate considerations. Both PCB trace length and connectors add to the capacitance of the TXS0108E-Q1 output. Therefore, TI recommends that this lumped-load capacitance is considered in order to avoid one-shot retriggering, bus contention, output signal oscillations, or other adverse system-level affects.

8.3.4 Enable and Disable

The TXS0108E-Q1 has an OE pin input that is used to disable the device by setting the OE pin low, which places all I/Os in the Hi-Z state. The disable time $(t_{\rm dis})$ indicates the delay between the time when the OE pin goes low and when the outputs actually get disabled (Hi-Z). The enable time $(t_{\rm en})$ indicates the amount of time the design must allow for the one-shot circuitry to become operational after the OE pin goes high.

8.3.5 Pull-up or Pull-down Resistors on I/O Lines

The TXS0108E-Q1 has the smart pull-up resistors dynamically change value based on whether a low or a high is being passed through the I/O line. Each A-port I/O has a pull-up resistor (R_{PUA}) to V_{CCA} and each B-port I/O has a pull-up resistor (R_{PUB}) to V_{CCB} . R_{PUA} and R_{PUB} have a value of 40 k Ω when the output is driving low. R_{PUA} and R_{PUB} have a value of 4 k Ω when the output is driving high. R_{PUA} and R_{PUB} are disabled when OE = Low. This feature provides lower static power consumption (when the I/Os are passing a low), and supports lower V_{OL} values for the same size pass-gate transistor, and helps improve simultaneous switching performance.

8.4 Device Functional Modes

The TXS0108E-Q1 device has two functional modes, enabled and disabled. To disable the device set the OE pin input low, which places all I/Os in a high impedance state. Setting the OE pin input high enables the device.



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TXS0108E-Q1 can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The device is ideal for use in applications where an open-drain driver is connected to the data I/Os. The device is appropriate for applications where a push-pull driver is connected to the data I/Os, but the TXB0104 device, (SCES650) 4-Bit Bidirectional Voltage-Level Translator might be a better option for such push-pull applications. The device is a semi-buffered auto-direction-sensing voltage translator design is optimized for translation applications (for example, MMC Card Interfaces) that require the system to start out in a low-speed open-drain mode and then switch to a higher speed push-pull mode.

9.2 Typical Application

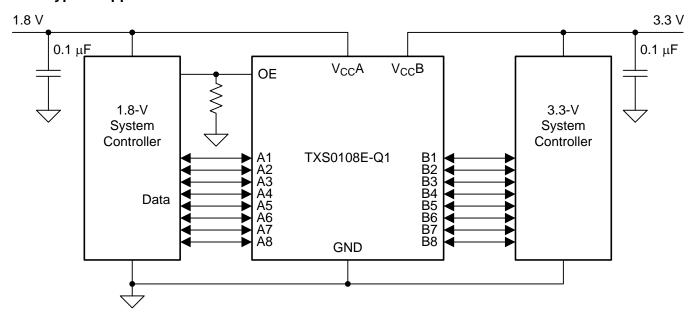


Figure 12. Typical Application Circuit

9.2.1 Design Requirements

For this design example, use the parameters listed in Table 1. Ensure that $V_{CCA} \le V_{CCB}$.

Table 1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	1.4 V to 3.6 V
Output voltage range	1.65 V to 5.5 V

9.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
 - Use the supply voltage of the device that is driving the TXS0108E-Q1 device to determine the input voltage range. For a valid logic high the value must exceed the V_{IH} of the input port. For a valid logic low the value must be less than the V_{IL} of the input port.



- Output voltage range
 - Use the supply voltage of the device that the TXS0108E-Q1 device is driving to determine the output voltage range.
 - The TXS0108E-Q1 device has smart internal pull-up resistors. External pull-up resistors can be added to reduce the total RC of a signal trace if necessary.
- An external pull-down resistor decreases the output VOH and VOL. Use Equation 1 to calculate the VOH as a
 result of an external pull-down resistor.

$$V_{OH} = V_{CCx} \times R_{PD} / (R_{PD} + 4 k\Omega)$$
 (1)

9.2.3 Application Curves

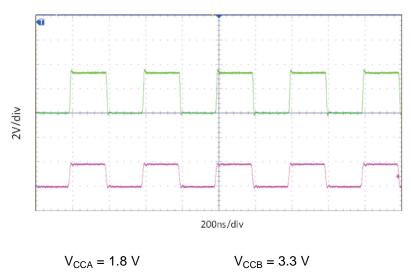


Figure 13. Level-Translation of a 2.5-MHz Signal



10 Power Supply Recommendations

During operation, ensure that $V_{CCA} \le V_{CCB}$ at all times. The sequencing of each power supply will not damage the device during the power up operation, so either power supply can be ramped up first. The output-enable (OE) input circuit is designed so that it is supplied by V_{CCA} and when the (OE) input is low, all outputs are placed in the high-impedance state. To ensure the high-impedance state of the outputs during power up or power down, the OE input pin must be tied to GND through a pull-down resistor and must not be enabled until V_{CCA} and V_{CCB} are fully ramped and stable. The minimum value of the pull-down resistor to ground is determined by the current-sourcing capability of the driver.

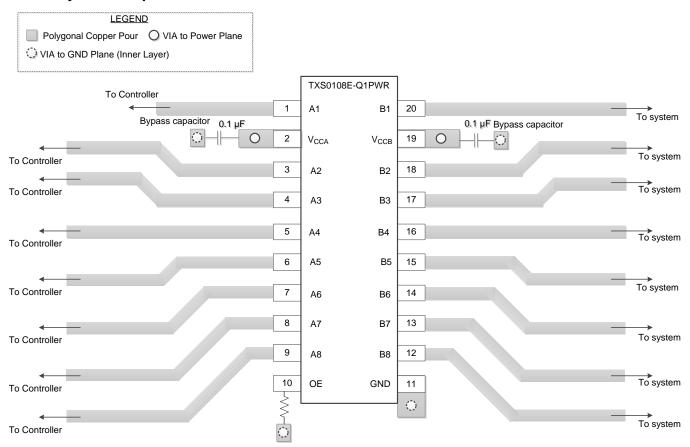
11 Layout

11.1 Layout Guidelines

To ensure reliability of the device, following common printed-circuit board layout guidelines is recommended.

- Bypass capacitors should be used on power supplies. Place the capacitors as close as possible to the VCCA, VCCB pin and GND pin.
- Short trace lengths should be used to avoid excessive loading.
- PCB signal trace-lengths must be kept short enough so that the round-trip delay of any reflection is less than
 the one shot duration, approximately 30 ns, ensuring that any reflection encounters low impedance at the
 source driver.

11.2 Layout Example



Keep OE low until V_{CCA} and V_{CCB} are powered up

Figure 14. Layout Example



12 器件和文档支持

12.1 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

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这些装置包含有限的内置 ESD 保护。 存储或装卸时,应将导线一起截短或将装置放置于导电泡棉中,以防止 MOS 门极遭受静电损伤。

12.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 机械、封装和可订购信息

以下页中包括机械、封装和可订购信息。这些信息是针对指定器件可提供的最新数据。这些数据会在无通知且不对本文档进行修订的情况下发生改变。欲获得该数据表的浏览器版本,请查阅左侧的导航栏。



PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
TXS0108EQPWRQ1	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	YF08EQ1	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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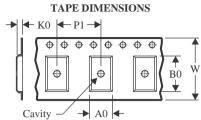
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PACKAGE MATERIALS INFORMATION

www.ti.com 3-Jun-2022

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

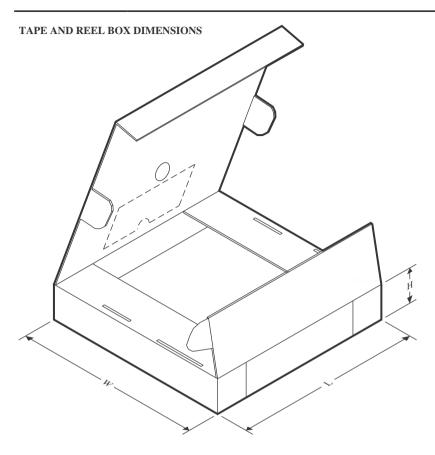


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TXS0108EQPWRQ1	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

www.ti.com 3-Jun-2022

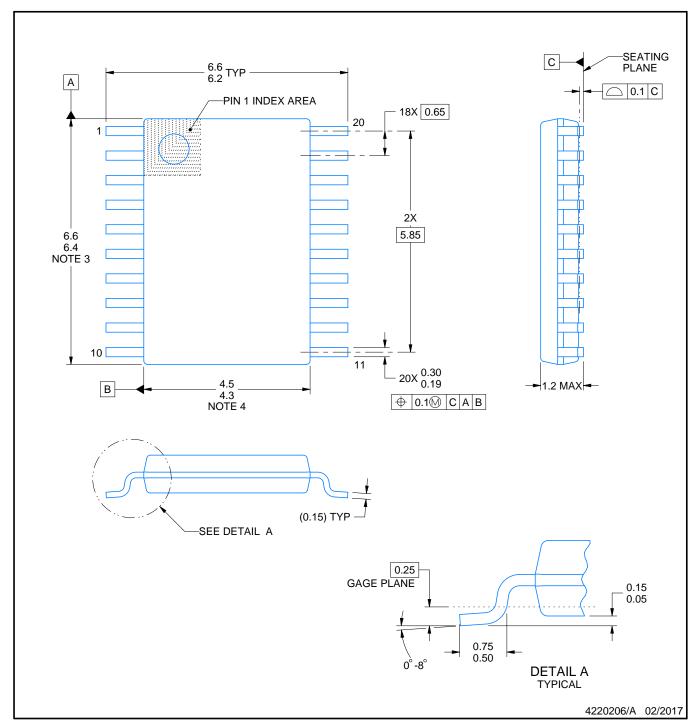


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TXS0108EQPWRQ1	TSSOP	PW	20	2000	356.0	356.0	35.0



SMALL OUTLINE PACKAGE



NOTES:

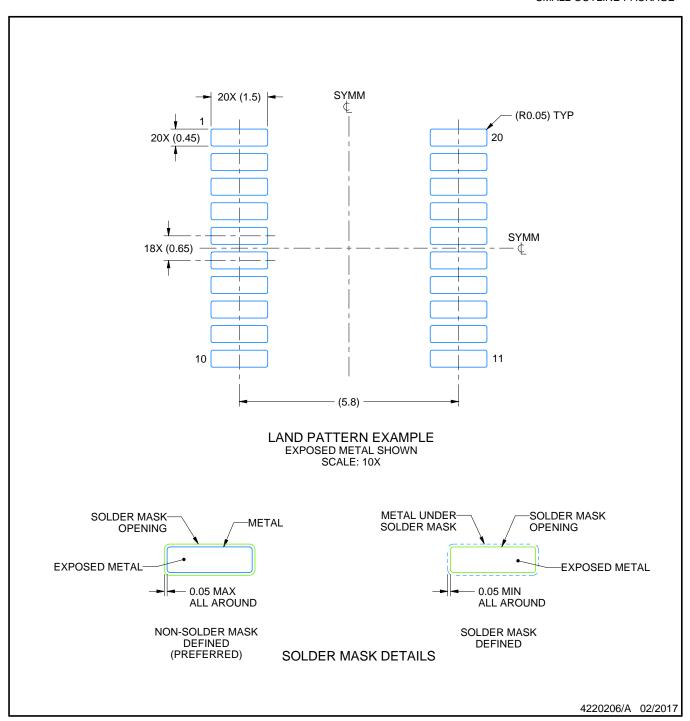
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



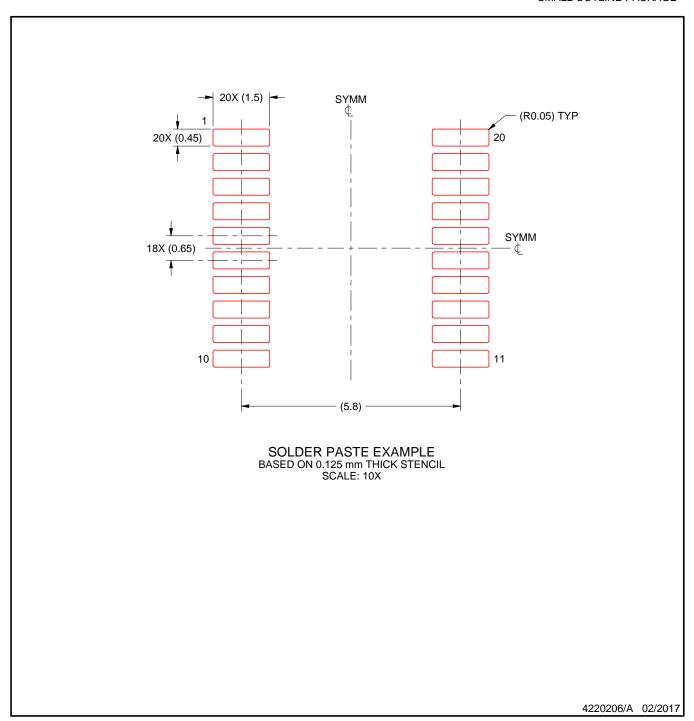
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



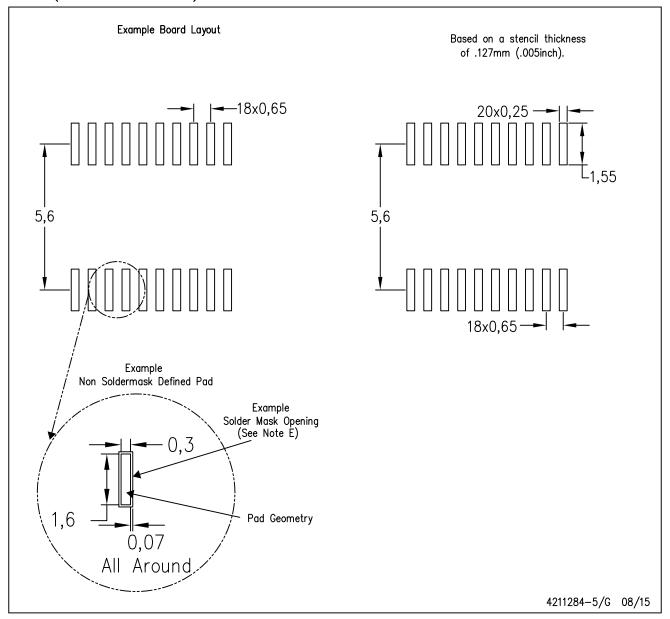
NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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